

Characteristics of a PV module

Manufacturer, model : **Trina Solar, TSM-400DE09**

Availability : Prod. Since 2021

Data source : UL 2021

STC power (manufacturer)	Pnom	400 Wp	Technology	Si-mono	
Module size (W x L)		1.096 x 1.754 m ²	Rough module area	Amodule	1.92 m ²
Number of cells		2 x 60	Sensitive area (cells)	Acells	1.76 m ²
Specifications for the model (manufacturer or measurement data)					
Reference temperature	TRef	25 °C	Reference irradiance	GRef	1000 W/m ²
Open circuit voltage	Voc	41.2 V	Short-circuit current	Isc	12.28 A
Max. power point voltage	Vmpp	34.2 V	Max. power point current	Impp	11.70 A
=> maximum power	Pmpp	400.1 W	Isc temperature coefficient	mulsc	4.9 mA/°C
One-diode model parameters					
Shunt resistance	Rshunt	160 ohm	Diode saturation current	IoRef	0.024 nA
Serie resistance	Rserie	0.14 ohm	Voc temp. coefficient	MuVoc	-131 mV/°C
Specified Pmax temper. coeff.	muPMaxR	-0.38 %/°C	Diode quality factor	Gamma	0.99
			Diode factor temper. coeff.	muGamma	-0.001 1/°C
Reverse Bias Parameters, for use in behaviour of PV arrays under partial shadings or mismatch					
Reverse characteristics (dark)	BRev	3.20 mA/V ²	(quadratic factor (per cell))		
Number of by-pass diodes per module		3	Direct voltage of by-pass diodes		-0.7 V

Model results for standard conditions (STC: T=25° C, G=1000 W/m², AM=1.5)

Max. power point voltage	Vmpp	34.7 V	Max. power point current	Impp	11.56 A
Maximum power	Pmpp	401.2 Wc	Power temper. coefficient	muPmpp	-0.37 %/°C
Efficiency(/ Module area)	Eff_mod	20.9 %	Fill factor	FF	0.793
Efficiency(/ Cells area)	Eff_cells	22.7 %			

